

## Features

- 1200 Watts peak pulse power ( $t_p = 8/20\mu s$ )
- DFN1608-2 package
- Unidirectional configurations
- Solid-state silicon-avalanche technology
- Low clamping voltage
- Low leakage current
- Normal capacitance ( $C_j = 150pF$ )
- Meet MSL level1, per J-STD-020, LF maximum peak of 260°C
- JESD22-A114-B ESD Voltage:HBM 30KV
- ESD Voltage :MM 0.4KV
- ESD Voltage :CDM 0.5KV
- Protection one data/power line to:
  - IEC 61000-4-2  $\pm 30kV$  contact  $\pm 30kV$  air
  - IEC 61000-4-4 (EFT) 40A (5/50ns)
  - IEC 61000-4-5 (Lightning) 23A (8/20  $\mu s$ )



## Mechanical Data

- **Case:** DFN1608-2 (plastic package)  
Lead free; RoHS compliant; Halogen free
- **Molding Compound Flammability Rating:**  
UL 94 V-0
- **Terminals:** High temperature soldering guaranteed:  
260 °C/10 sec. at terminals

## Applications

- Computers and peripherals
- Digital Cameras
- Audio and video equipment
- Cellular handsets and accessories
- Portable electronics
- Power supply protection

## Absolute Maximum Ratings

Ratings at 25 °C, ambient temperature unless otherwise specified

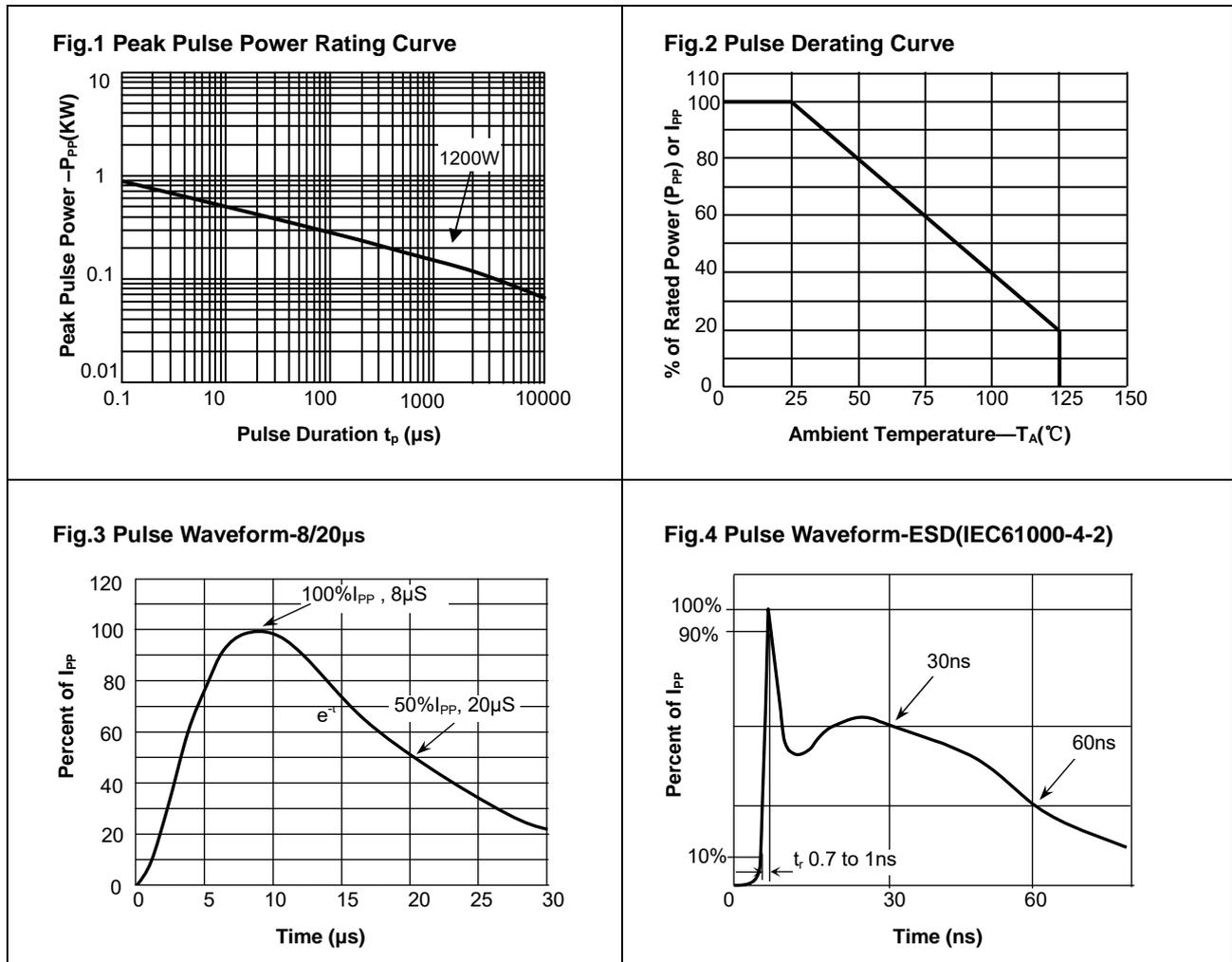
Parameter	Symbol	Value	Unit
Peak Pulse Power ( $T_p = 8/20\mu s$ )	$P_{PP}$	1200	W
ESD contact/air discharge (IEC-61000-4-2)	$V_{ESD}$	30/30	kV
Peak Pulse Current ( $t_p = 8/20\mu s$ )	$I_{PP}$	23.0	A
Junction Temperature	$T_J$	-55 to +125	°C
Storage temperature	$T_{STG}$	-55 to +150	°C

## Electrical Characteristics

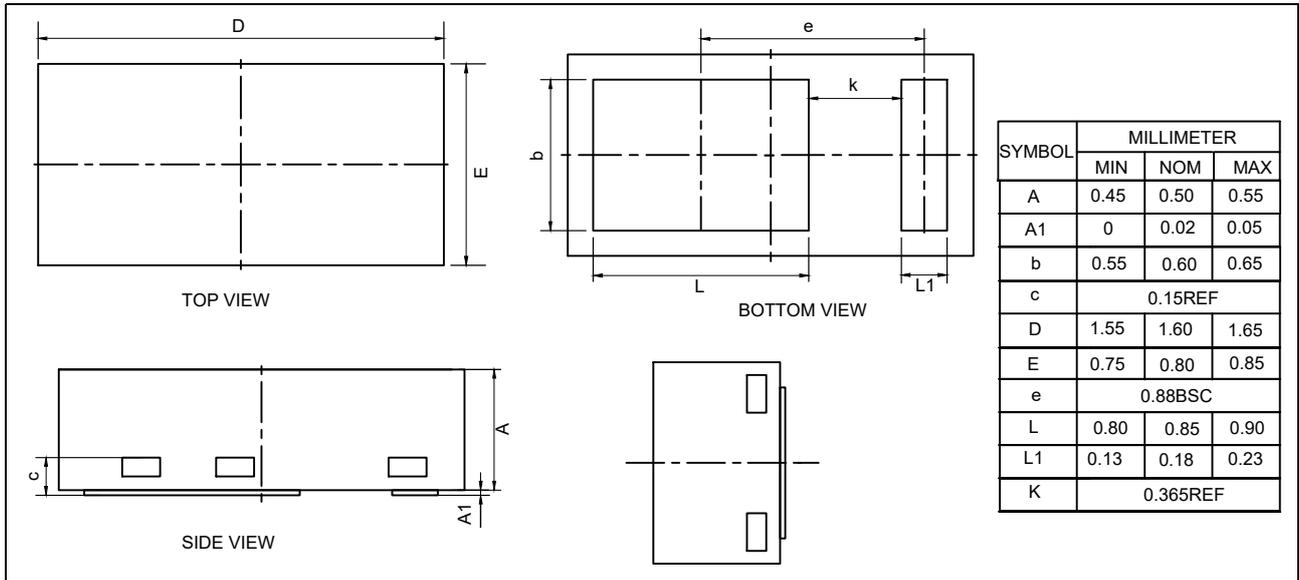
( $T_A = 25$  °C unless otherwise specified)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Reverse stand-off Voltage	$V_{RWM}$				24	V
Reverse Breakdown Voltage	$V_{BR}$	$I_T = 1mA$	27	30	36	V
Reverse Leakage Current	$I_R$	$V_R = 24V$			0.1	$\mu A$
Clamping Voltage (IEC 61000-4-5)	$V_C$	$I_{PP} = 23A$			65	V
Junction Capacitance	$C_J$	$V_R = 0V, f = 1MHz$		150	160	pF

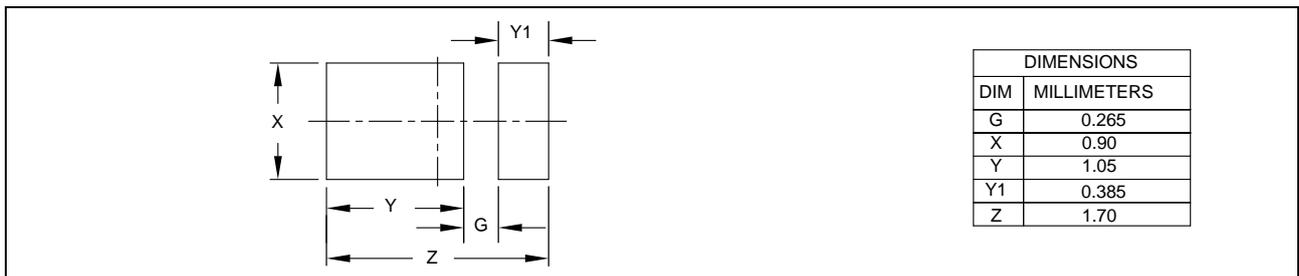
**Typical Characteristics** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$  unless otherwise specified)



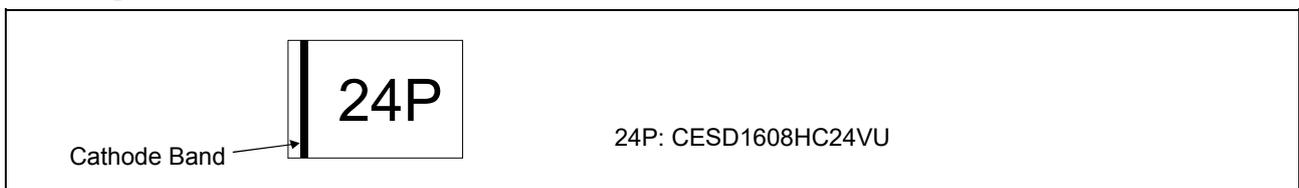
**Package Dimensions**



**Pad Dimensions**



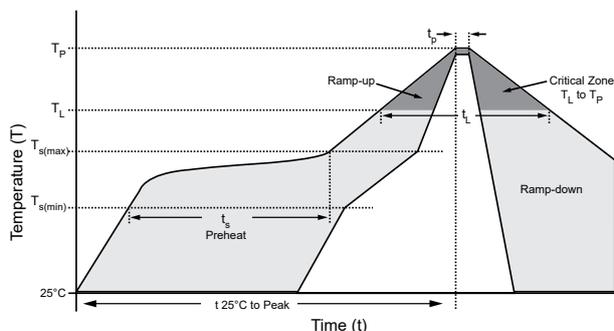
**Marking**



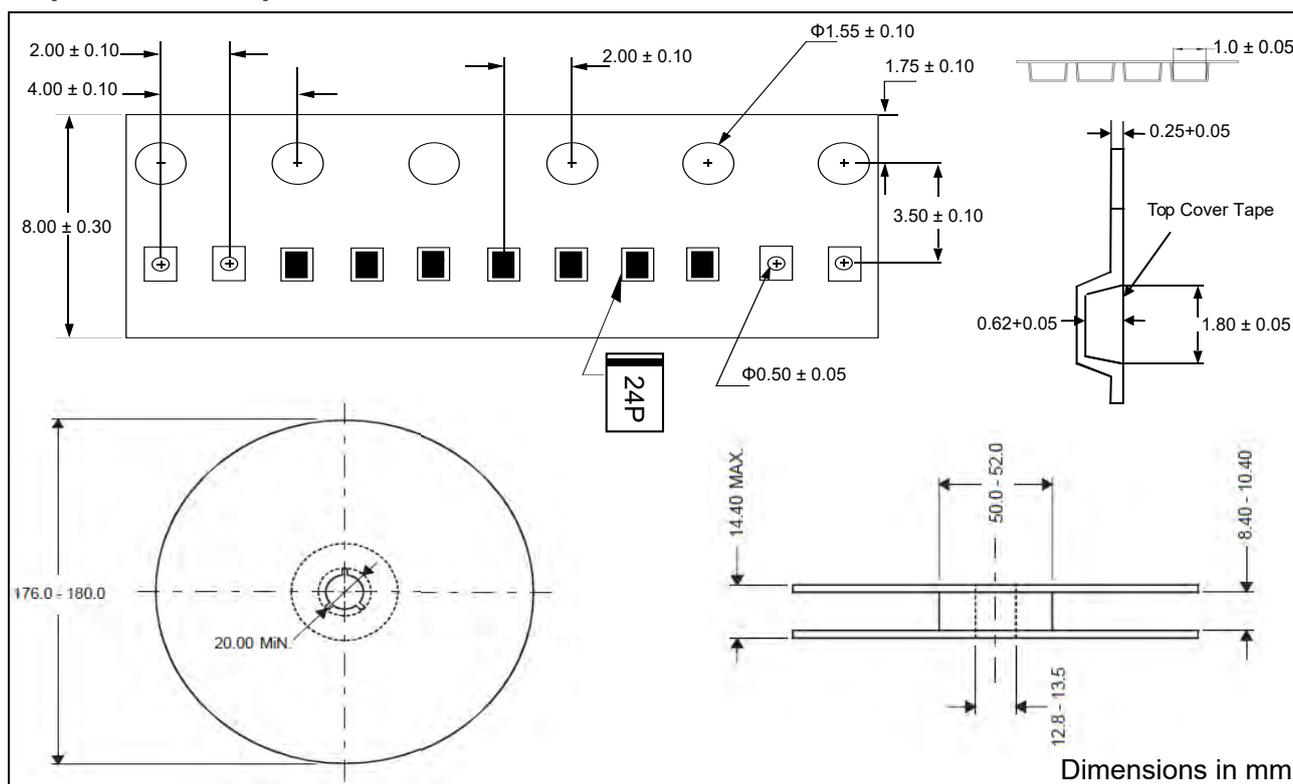
### Suggested thermal profile for soldering process

1. Storage environment : Temperature=5~40°C Humidity=55±25%
2. Reflow soldering of surface-mount device
3. Reflow soldering

Profile Feature	Soldering Condition
Average ramp-up rate( $T_L$ to $T_P$ )	<3°C/sec
Preheat	
- Temperature Min( $T_{smin}$ )	150°C
- Temperature Max( $T_{smax}$ )	200°C
- Time(min to max)( $t_s$ )	60~120sec
$T_{smax}$ to $T_L$	
- Ramp-up Rate	<3sec
Time maintained above:	
- Temperature ( $T_L$ )	217°C
- Time( $t_L$ )	60-260sec
Peak Temperature( $T_P$ )	255 -0/+5°C
Time within 5°C of actual Peak Temperature( $T_P$ )	10~30sec
Ramp-down Rate	<6°C/sec
Time 25°C to Peak Temperature	<6minutes



### Tape and Reel Specification



### Ordering information

Order code	Package	Packaging option	Base quantity	Packaging specification
YED16H22423AV	DFN1608-2	Tape and reel	3000pcs / reel	EIA STD RS-481